

Polar™ **Power MOSFET**

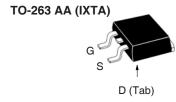
IXTA14N60P IXTP14N60P IXTQ14N60P

600V **14A** ≤ $550 m\Omega$ $\mathbf{R}_{\mathrm{DS(on)}}$

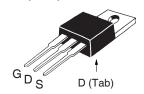
Enhancement Mode Avalanche Rated



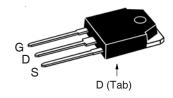
Symbol	Test Conditions	Maximum Ratings		
V _{DSS}	T _J = 25°C to 150°C	600	V	
V _{DGR}	$T_J = 25$ °C to 150°C, $R_{GS} = 1M\Omega$	600	V	
V _{GSS}	Continuous	±30	V	
V _{GSM}	Transient	±40	V	
I _{D25}	T _C = 25°C	14	A	
$I_{\rm DM}$	$T_{\rm C} = 25^{\circ}{\rm C}$, pulse width limited by $T_{\rm JM}$	42	Α	
I _A	T _C = 25°C	14	A	
E _{AS}	T _C = 25°C	900	mJ	
P _D	T _C = 25°C	300	W	
T		-55 +150	°C	
T _{JM}		150	°C	
T _{stg}		-55 +150	°C	
T,	Maximum Lead Temperature for Soldering	300	°C	
T _{SOLD}	Plastic Body for 10s	260	°C	
M _d	Mounting torque (TO-220 &TO-3P)	1.13/10	Nm/lb.in.	
Weight	TO-263	2.5	g	
	TO-220	3.0	g	
	TO-3P	5.5	g	



TO-220AB (IXTP)



TO-3P (IXTQ)



G = Gate	D	=	Drain
S = Source	Tab	=	Drain

Features

- International Standard Packages
- Fast Intrinsic Rectifier
- Avalanche Rated
- Low R_{DS(ON)} and Q_G
 Low Package Inductance

Advantages

- High Power Density
- Easy to Mount
- Space Savings

Applications

- Switch-Mode and Resonant-Mode **Power Supplies**
- DC-DC Converters
- Laser Drivers
- AC and DC Motor Drives
- Robotics and Servo Controls

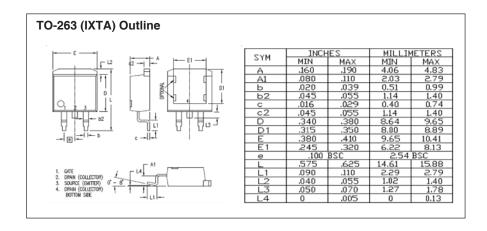
			acterist Typ.	ic Values Max.
BV _{DSS}	$V_{GS} = 0V, I_D = 250\mu A$	600		V
V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	3.0		5.5 V
I _{GSS}	$V_{GS} = \pm 30V, V_{DS} = 0V$			±100 nA
I _{DSS}	$V_{DS}^{}=V_{DSS}^{},\ V_{GS}^{}=0V$ $T_{_{J}}^{}=125^{\circ}C$			5 μA 100 μA
R _{DS(on)}	$V_{GS} = 10V, I_{D} = 0.5 \cdot I_{D25}, \text{ Note 1}$		450	550 mΩ

.,		aracteristic Values Typ. ∣ Max.			
g _{fs}		V _{DS} = 20V, I _D = 0.5 • I _{D25} , Note 1	7	13	S
C _{iss})			2500	pF
C _{oss}	}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		215	pF
\mathbf{C}_{rss}	J			13	pF
t _{d(on)}	٦	Resistive Switching Times		23	ns
t,		•		27	ns
t _{d(off)}	7	$V_{gS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		70	ns
t,)	$R_{\rm G} = 10\Omega \text{ (External)}$		26	ns
$\mathbf{Q}_{g(on)}$)			36	nC
Q_{gs}	}	$V_{GS} = 10V$, $V_{DS} = 0.5 \cdot V_{DSS}$, $I_{D} = 0.5 \cdot I_{D25}$		16	nC
\mathbf{Q}_{gd}	J			12	nC
R _{thJC}					0.42 °C/W
$\mathbf{R}_{\mathrm{thCS}}$		(TO-220) (TO-3P		0.50 0.25	°C/W °C/W

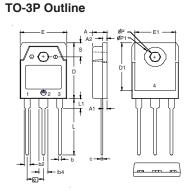
Source-Drain Diode

			aracteristic Values		
$(1_{J} = 25 \text{ C},$	unless otherwise specified)	Min.	Тур.	Max.	
I _s	$V_{GS} = 0V$			14	Α
I _{sm}	Repetitive, pulse width limited by $T_{_{JM}}$			42	Α
V _{SD}	$I_F = I_S$, $V_{GS} = 0V$, Note 1			1.5	V
t _{rr}	$I_F = 14A$, -di/dt = 100A/ μ s $V_R = 100V$, $V_{GS} = 0V$		500		ns

Note 1: Pulse test, $t \le 300\mu s$; duty cycle, $d \le 2\%$.



TO-220 Outline 3X b2-1 - Gate 2.4 - Drain 3 - Source MILLIMETERS SYM MAX 4.70 MA) MIN .169 .185 1.40 2.70 .055 1.20 .047 .079 A1 Α2 .024 .045 0.60 1.00 1.15 0.35 Ь2 1.45 .014 .587 .335 .500 .026 .626 .370 14.90 15.90 8.50 9.40 12.70 13.50 9.70 10.30 .531 (D2) .406 .323 382 (E1) 7.20 2.54 BSC 5.08 BSC .283 8.20 е e 1 .244 .**4**92 6.80 13.90 H1 6.20 12.50 2.80



.150

3.40 2.70 3.80 3.20

ØΡ

Q

134

PINS: 1 - Gate 2, 4 - Drain 3 - Source

SYM	INCH	INCHES		MILLIMETERS		
2110	MIN	MAX	MIN	MAX		
Α	.185	.193	4.70	4.90		
Α1	.051	.059	1.30	1.50		
A2	.057	.065	1.45	1.65		
Ф	.035	.045	0.90	1.15		
b2	.075	.087	1.90	2.20		
b4	.114	.126	2.90	3.20		
С	.022	.031	0.55	0.80		
D	.780	.799	19.80	20.30		
D1	.665	.677	16.90	17.20		
Е	.610	.622	15.50	15.80		
E1	.531	.539	13.50	13.70		
е	.215 BSC		5.45 BSC			
L	.779	.795	19.80	20.20		
L1	.134	.142	3.40	3.60		
ØΡ	.126	.134	3.20	3.40		
øP1	.272	.280	6.90	7.10		
S	.193	.201	4.90	5.10		



Fig. 1. Output Characteristics @ T_J = 25°C

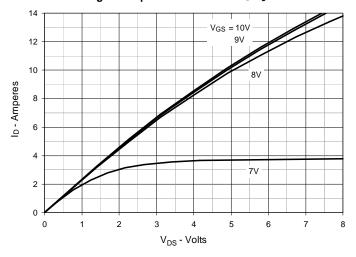


Fig. 2. Extended Output Characteristics @ T_J = 25°C

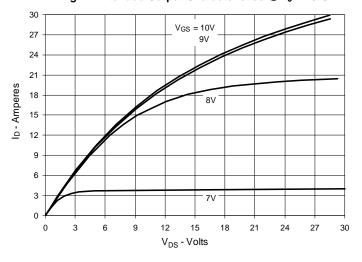


Fig. 3. Output Characteristics @ T_J = 125°C

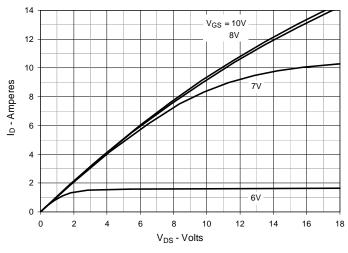


Fig. 4. $R_{DS(on)}$ Normalized to I_D = 7A Value vs. Junction Temperature

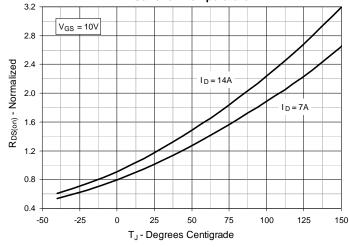


Fig. 5. $R_{DS(on)}$ Normalized to $I_D = 7A$ Value vs.

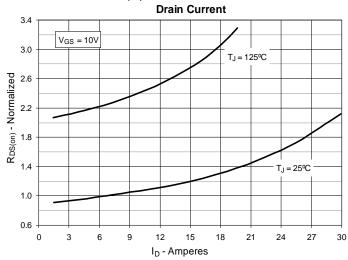
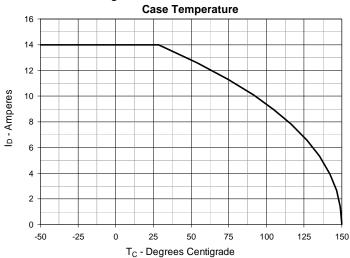
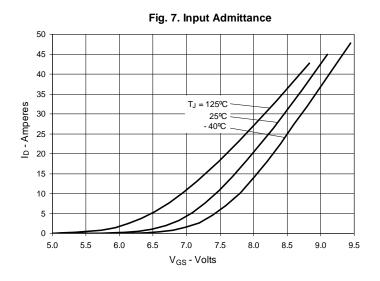
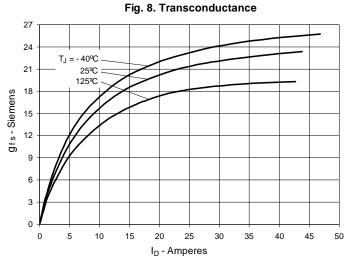


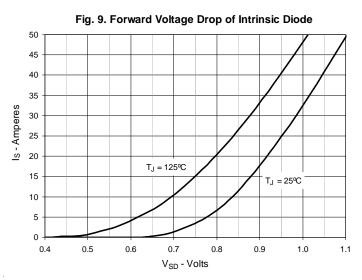
Fig. 6. Maximum Drain Current vs.

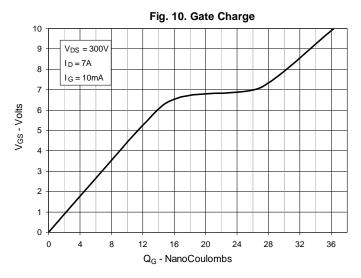


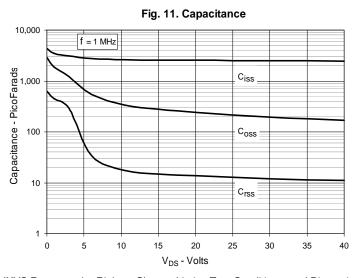


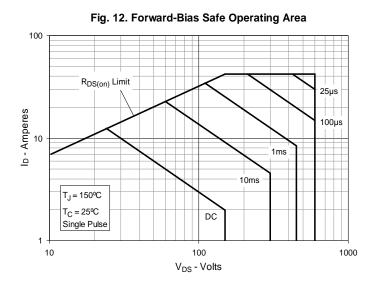












 $\ensuremath{\mathsf{IXYS}}$ Reserves the Right to Change Limits, Test Conditions, and Dimensions.



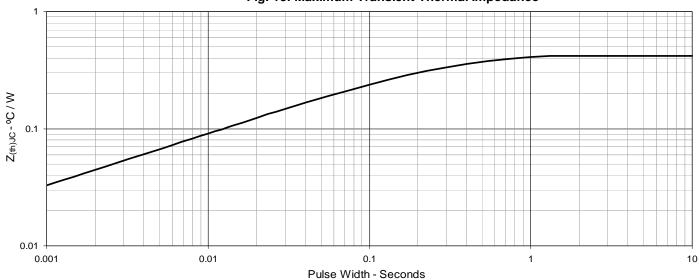


Fig. 13. Maximum Transient Thermal Impedance

